

**P6SMB-E Series**



**OBSOLETE** DATE: 08/21/202 PCN/ECN# 41356  
REPLACED BY: P6SMB

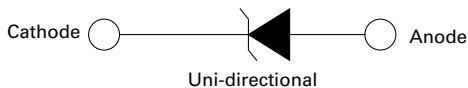


**Maximum Ratings and Thermal Characteristics  
(T<sub>A</sub>=25°C unless otherwise noted)**

Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T <sub>A</sub> =25°C by 10/1000µs Waveform (Fig.2)(Note 1), (Note 2)	P <sub>PPM</sub>	600	W
Power Dissipation on Infinite Heat Sink at T <sub>L</sub> =50°C	P <sub>D</sub>	5.0	W
Peak Forward Surge Current, 8.3ms Single Half Sine Wave (Note 3)	I <sub>FSM</sub>	100	A
Maximum Instantaneous Forward Voltage at 50A for Unidirectional Only	V <sub>F</sub>	3.5	V
Operating Temperature Range	T <sub>J</sub>	-65 to 150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to 175	°C
Typical Thermal Resistance Junction to Lead	R <sub>JL</sub>	20	°C/W
Typical Thermal Resistance Junction to Ambient	R <sub>JA</sub>	100	°C/W

- Notes:**
1. Non-repetitive current pulse, per Fig. 4 and derated above T<sub>J</sub> (initial) =25°C per Fig. 3.
  2. Mounted on copper pad area of 0.2x0.2" (5.0 x 5.0mm) to each terminal.
  3. Measured on 8.3ms single half sine wave or equivalent square wave for unidirectional device only, duty cycle=4 per minute maximum.

**Functional Diagram**



**Description**

The P6SMB-E series is designed specifically to protect sensitive electronic equipment from voltage transients induced by lightning and other transient voltage events.

**Features**

- Excellent clamping capability
- Low incremental surge resistance
- For surface mounted applications to optimize board space
- Low profile package
- Typical failure mode is short from over-specified voltage or current
- Whisker test is conducted based on JEDEC JESD201A per its table 4a and 4c
- IEC 61000-4-2 ESD 30kV(Air), 30kV (Contact)
- EFT protection of data lines in accordance with IEC 61000-4-4
- Built-in strain relief
- Fast response time: typically less than 1.0ps from 0V to BV min
- 600W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycles):0.01 %
- High temperature to reflow soldering guaranteed: 260°C/40sec
- V<sub>BR</sub> @T<sub>J</sub> = V<sub>BR</sub> @25°C x (1+αT x (T<sub>J</sub> - 25)) (αT:Temperature Coefficient, typical value is 0.1%)
- EPI silicon technology
- Meet MSL level1, per J-STD-020C, LF maximum peak of 260°C
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

**Applications**

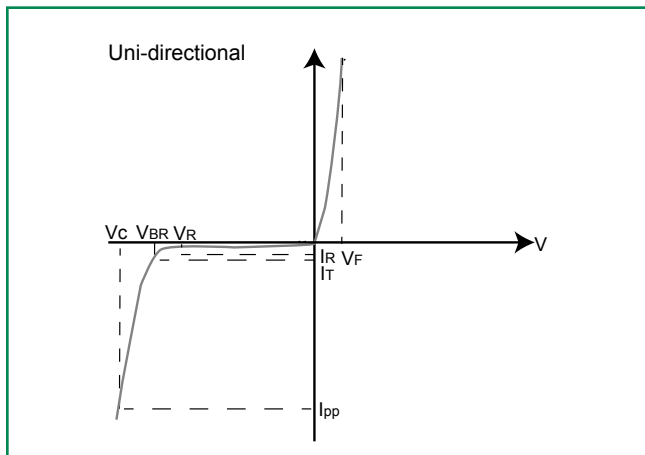
TVS devices are ideal for the protection of I/O Interfaces, V<sub>CC</sub> bus and other vulnerable circuits used in Telecom, Computer, Industrial and Consumer electronic applications.

### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Part Number (Uni)	Marking	Reverse Stand off Voltage V <sub>R</sub> (Volts)	Breakdown Voltage V <sub>BR</sub> (Volts) @ I <sub>T</sub>		Test Current I <sub>T</sub> (mA)	Maximum Clamping Voltage V <sub>C</sub> @ I <sub>pp</sub> (V)	Maximum Peak Pulse Current I <sub>pp</sub> (A)	Maximum Reverse Leakage I <sub>R</sub> @ V <sub>R</sub> (μA)
			MIN	MAX				
P6SMB350A-E	350S	300	332.0	368.0	1	482.0	1.30	1
P6SMB400A-E	400S	342	380.0	420.0	1	548.0	1.10	1
P6SMB440A-E	440S	376	418.0	462.0	1	602.0	1.00	1
P6SMB480A-E*	480S	408	456.0	504.0	1	658.0	0.95	1
P6SMB510A-E*	510S	434	485.0	535.0	1	698.0	0.86	1
P6SMB530A-E*	530S	451	503.5	556.5	1	725.0	0.83	1
P6SMB540A-E*	540S	460	513.0	567.0	1	740.0	0.82	1
P6SMB550A-E*	550S	468	522.5	577.5	1	760.0	0.79	1
P6SMB600A-E*	600S	510	570.0	630.0	1	822.0	0.73	1
P6SMB650A-E*	650S	553	617.5	682.5	1	891.0	0.68	1
P6SMB700A-E*	700S	595	665.0	735.0	1	959.0	0.63	1
P6SMB800A-E*	800S	680	760.0	840.0	1	1096.0	0.55	1
P6SMB900A-E*	900S	765	855.0	945.0	1	1233.0	0.50	1
P6SMB1000A-E*	1000S	850	950.0	1050.0	1	1365.0	0.44	1

Note: for parts with \* are still under development

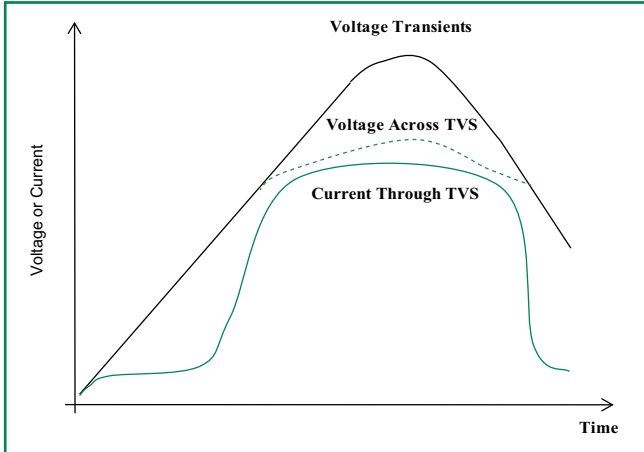
### I-V Curve Characteristics



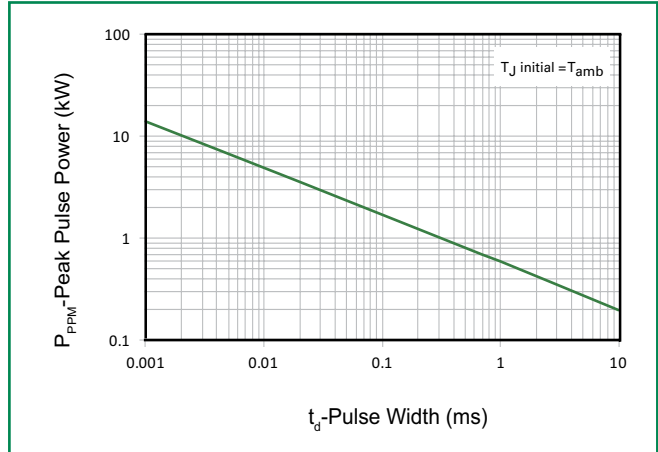
- P<sub>PPM</sub>** Peak Pulse Power Dissipation – Max power dissipation
- V<sub>R</sub>** Stand-off Voltage – Maximum voltage that can be applied to the TVS without operation
- V<sub>BR</sub>** Breakdown Voltage – Maximum voltage that flows through the TVS at a specified test current (I<sub>T</sub>)
- V<sub>C</sub>** Clamping Voltage – Peak voltage measured across the TVS at a specified I<sub>ppm</sub> (peak impulse current)
- I<sub>R</sub>** Reverse Leakage Current – Current measured at V<sub>R</sub>
- V<sub>F</sub>** Forward Voltage Drop for Uni-directional

**Ratings and Characteristic Curves** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

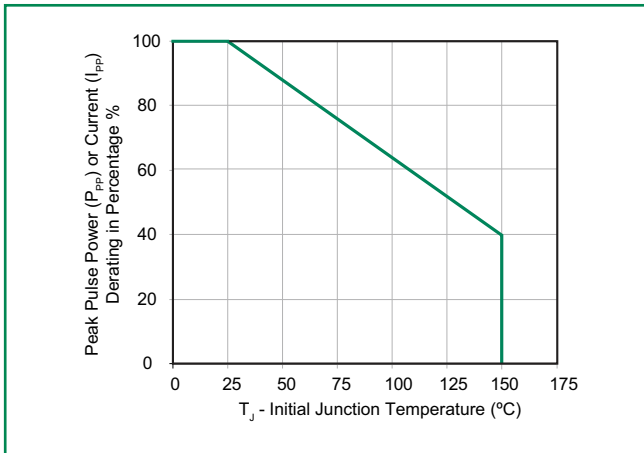
**Figure 1 - TVS Transients Clamping Waveform**



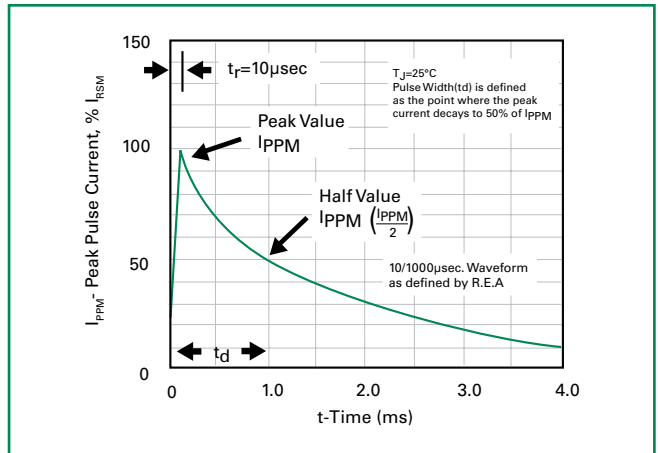
**Figure 2 - Peak Pulse Power Rating**



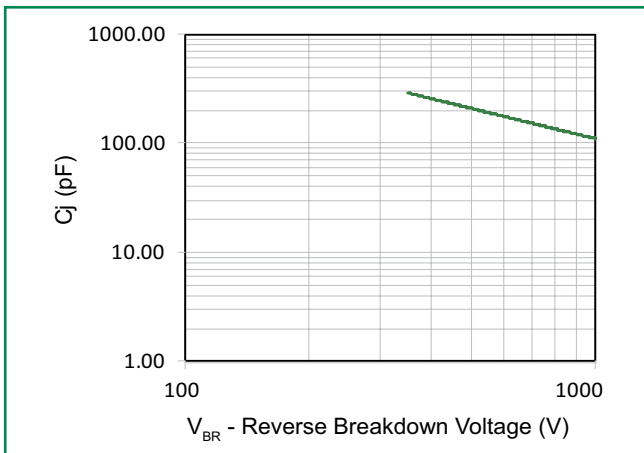
**Figure 3 - Peak Pulse Power Derating Curve**



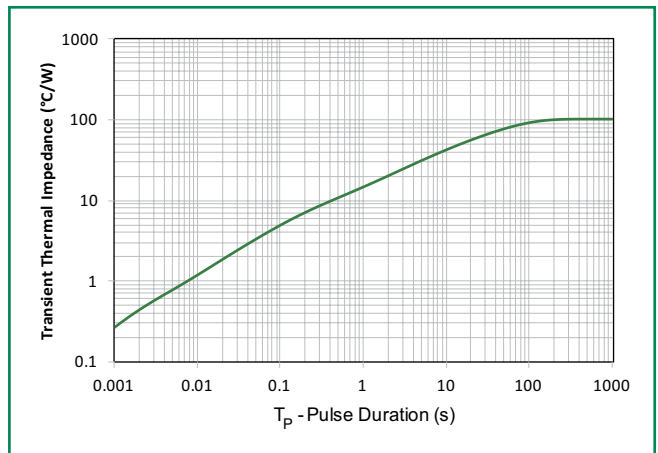
**Figure 4 - Pulse Waveform**



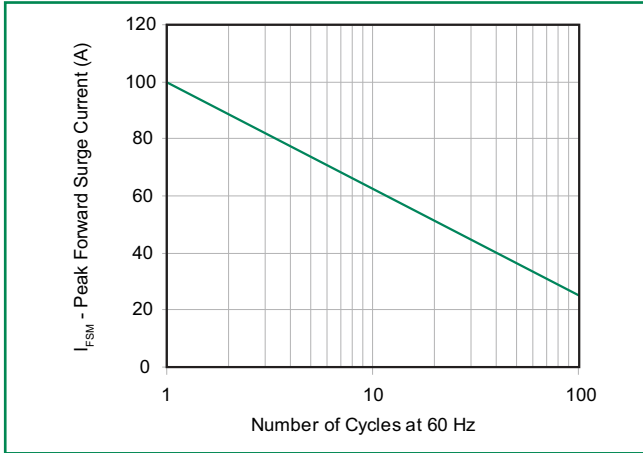
**Figure 5 - Typical Junction Capacitance**



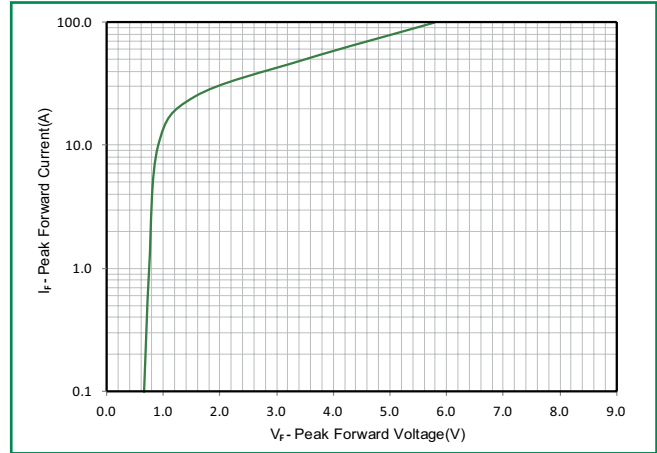
**Figure 6 - Typical Transient Thermal Impedance**



**Figure 7 - Maximum Non-Repetitive Peak Forward Surge Current Uni-Directional Only**

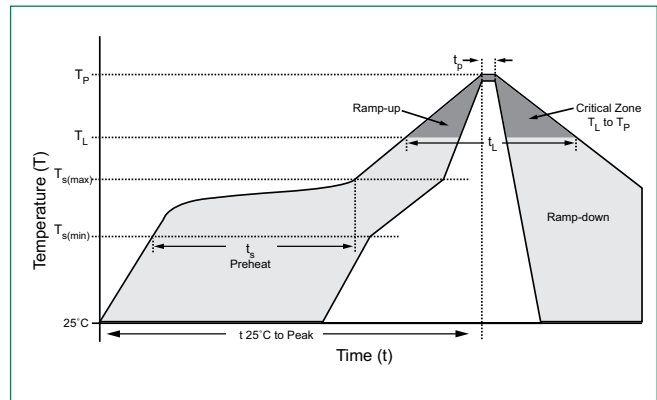


**Figure 8 - Peak Forward Voltage Drop vs Peak Forward Current (Typical Values)**



**Soldering Parameters**

Reflow Condition	Lead-free assembly	
Pre Heat	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 180 secs
Average ramp up rate (Liquidus Temp ( $T_A$ ) to peak)	3°C/second max	
$T_{s(max)}$ to $T_A$ - Ramp-up Rate	3°C/second max	
Reflow	- Temperature ( $T_A$ ) (Liquidus)	217°C
	- Time (min to max) ( $t_r$ )	60 – 150 seconds
Peak Temperature ( $T_p$ )	260 <sup>+0/-5</sup> °C	
Time within 5°C of actual peak Temperature ( $t_p$ )	20 – 40 seconds	
Ramp-down Rate	6°C/second max	
Time 25°C to peak Temperature ( $T_p$ )	8 minutes Max.	
Do not exceed	260°C	



**Physical Specifications**

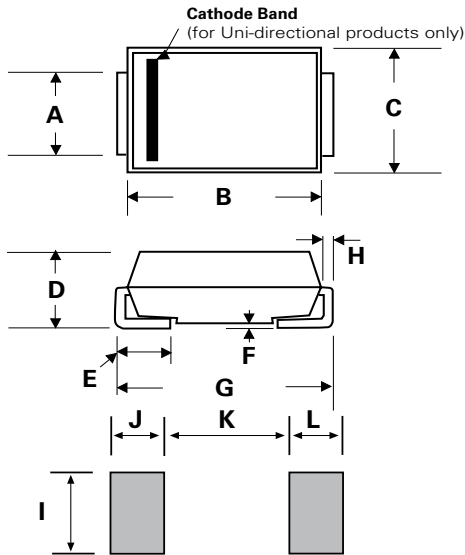
<b>Weight</b>	0.003 ounce, 0.093 grams
<b>Case</b>	JEDEC DO214AA. Molded plastic body over glass passivated junction
<b>Polarity</b>	Color band denotes cathode except Bidirectional
<b>Terminal</b>	Matte Tin-plated leads, Solderable per JESD22-B102

**Environmental Specifications**

<b>High Temp. Storage</b>	JESD22-A103
<b>HTRB</b>	JESD22-A108
<b>Temperature Cycling</b>	JESD22-A104
<b>MSL</b>	JEDEC-J-STD-020, Level 1
<b>H3TRB</b>	JESD22-A101
<b>RSH</b>	JESD22-A111

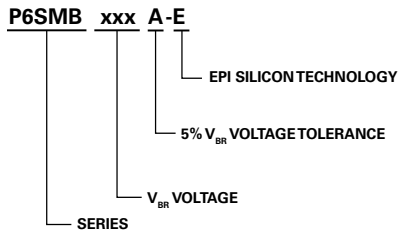
**Dimensions**

**DO-214AA (SMB J-Bend)**

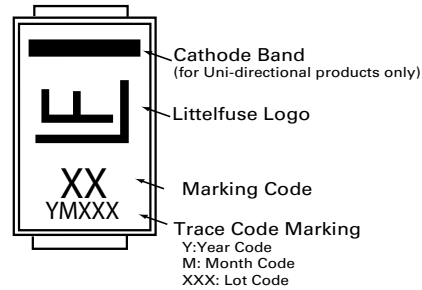


Dimensions	Inches		Millimeters	
	Min	Max	Min	Max
A	0.076	0.086	1.930	2.200
B	0.160	0.187	4.060	4.750
C	0.130	0.155	3.300	3.940
D	0.078	0.103	1.990	2.610
E	0.030	0.060	0.760	1.520
F	-	0.008	-	0.203
G	0.205	0.220	5.210	5.590
H	0.006	0.012	0.152	0.305
I	0.089	-	2.260	-
J	0.085	-	2.160	-
K	-	0.107	-	2.740
L	0.085	-	2.160	-

**Part Numbering System**



**Part Marking System**



**Packaging**

Part number	Component Package	Quantity	Packaging Option	Packaging Specification
P6SMBxxx A-E	DO-214AA	3000	Tape & Reel - 12mm tape/13" reel	EIA STD RS-481

**Tape and Reel Specification**

